General Purpose Transistors PNP Silicon

Features

- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	-60	Vdc
Collector-Base Voltage	V _{CBO}	-60	Vdc
Emitter-Base Voltage	V _{EBO}	-5.0	Vdc
Collector Current – Continuous	Ι _C	-600	mAdc
Collector Current – Peak (Note 3)	I _{CM}	-1200	mAdc

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Total Device Dissipation – FR–5 Board (Note 1) @T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	556	°C/W
Total Device Dissipation – Alumina Substrate, (Note 2) @T _A = 25°C Derate above 25°C	P _D	300 2.4	mW mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	417	°C/W
Total Device Dissipation – Heat Spreader or equivalent, (Note 4) @T _A = 25°C	P _D	350	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	357	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

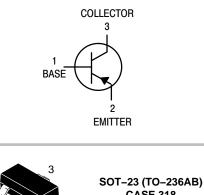
3. Reference SOA curve.

4. Heat Spreader or equivalent = 450 mm^2 , 2 oz.



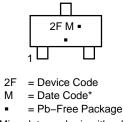
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MARKING DIAGRAM



(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBT2907ALT1G	SOT-23	3000 / Tape &
SMMBT2907ALT1G	(Pb-Free)	Reel
MMBT2907ALT3G	SOT-23	10,000 / Tape &
SMMBT2907ALT3G	(Pb-Free)	Reel

⁺For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

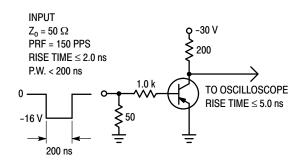
^{1.} FR-5 = $1.0 \times 0.75 \times 0.062$ in. 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Charac	teristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS					
$\label{eq:collector} \begin{array}{l} \mbox{Collector}-\mbox{Emitter Breakdown Voltage (Not (I_C = -1.0 \mbox{ mAdc}, I_B = 0) \\ (I_C = -10 \mbox{ mAdc}, I_B = 0) \end{array}$	e 5)	V _{(BR)CEO}	-60 -60		Vdc
Collector-Base Breakdown Voltage (I _C =	= –10 μAdc, I _E = 0)	V _{(BR)CBO}	-60	-	Vdc
Emitter-Base Breakdown Voltage (I _E = -	-10 μAdc, I _C = 0)	V _{(BR)EBO}	-5.0	-	Vdc
Collector Cutoff Current ($V_{CE} = -30$ Vdc,	V _{EB(off)} = -0.5 Vdc)	ICEX	-	-50	nAdc
$ Collector Cutoff Current \\ (V_{CB} = -50 \text{ Vdc}, I_E = 0) \\ (V_{CB} = -50 \text{ Vdc}, I_E = 0, T_A = 125^\circ\text{C}) $		Ісво		-0.010 -10	μAdc
Base Cutoff Current (V _{CE} = -30 Vdc, V _{EE}	_{8(off)} = -0.5 Vdc)	I _{BL}	-	-50	nAdc
ON CHARACTERISTICS					
$ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = -0.1 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -1.0 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -10 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -150 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \\ (I_{C} = -500 \text{ mAdc}, V_{CE} = -10 \text{ Vdc}) \end{array} $	e 5)	h _{FE}	75 100 100 100 50	- - 300 -	_
Collector – Emitter Saturation Voltage (Not ($I_C = -150$ mAdc, $I_B = -15$ mAdc) (Not ($I_C = -500$ mAdc, $I_B = -50$ mAdc)		V _{CE(sat)}		-0.4 -1.6	Vdc
$\begin{array}{l} \text{Base}-\text{Emitter Saturation Voltage (Note 5)} \\ (\text{I}_{\text{C}}=-150 \text{ mAdc}, \text{ I}_{\text{B}}=-15 \text{ mAdc}) \\ (\text{I}_{\text{C}}=-500 \text{ mAdc}, \text{ I}_{\text{B}}=-50 \text{ mAdc}) \end{array}$	5)	V _{BE(sat)}		-1.3 -2.6	Vdc
SMALL-SIGNAL CHARACTERISTICS				-	
Current-Gain – Bandwidth Product (Not $(I_C = -50 \text{ mAdc}, V_{CE} = -20 \text{ Vdc}, f = 10)$		f _T	200	-	MHz
Output Capacitance ($V_{CB} = -10$ Vdc, $I_E =$	= 0, f = 1.0 MHz)	C _{obo}	-	8.0	pF
Input Capacitance (V_{EB} = -2.0 Vdc, I_C = 0, f = 1.0 MHz)		C _{ibo}	-	30	
SWITCHING CHARACTERISTICS					
Turn–On Time		t _{on}	-	45	
Delay Time	$(V_{CC} = -30 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = -15 \text{ mAdc})$	t _d	-	10	
Rise Time		t _r	-	40	
Turn–Off Time		t _{off}	-	100	ns
Storage Time	$(V_{CC} = -6.0 \text{ Vdc}, I_C = -150 \text{ mAdc}, I_{B1} = I_{B2} = -15 \text{ mAdc})$	t _s	-	80	
Fall Time		t _f	_	30	

5. Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 2.0%.

6. f_T is defined as the frequency at which $|h_{fe}|$ extrapolates to unity.





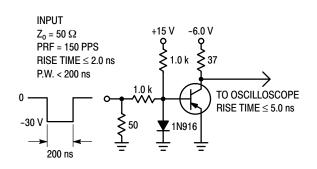
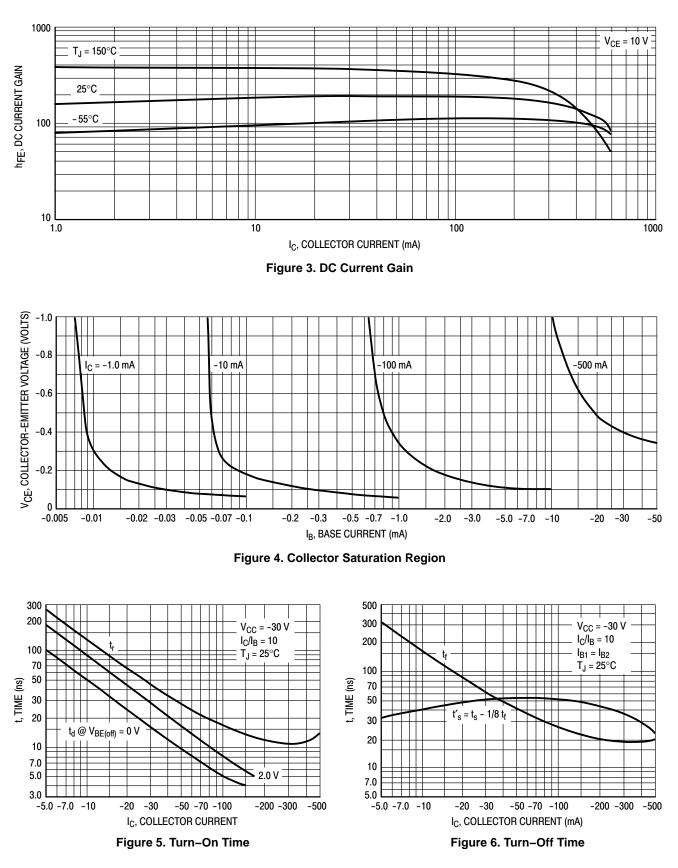


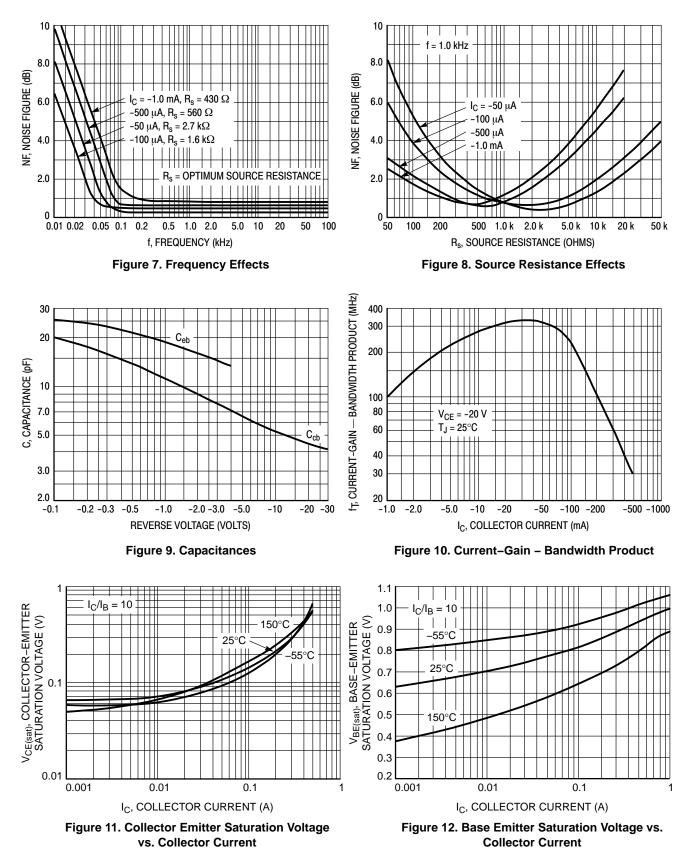
Figure 2. Storage and Fall Time Test Circuit

TYPICAL CHARACTERISTICS



TYPICAL SMALL-SIGNAL Characteristics NOISE FIGURE

 V_{CE} = 10 Vdc, T_A = 25°C



TYPICAL SMALL-SIGNAL Characteristics NOISE FIGURE

 V_{CE} = 10 Vdc, T_A = 25°C

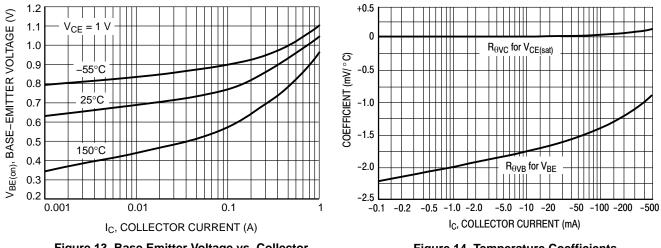




Figure 14. Temperature Coefficients

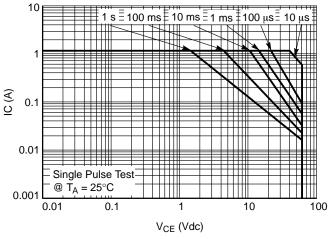


Figure 15. Safe Operating Area





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